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**[LM5157](https://www.ti.com/product/LM5157)** [SNVSBK7](https://www.ti.com/lit/pdf/SNVSBK7) – JULY 2021

# LM5157 2.2-MHz Wide V<sub>IN</sub> 50-V Boost/SEPIC/Flyback Converter with Dual Random **Spread Spectrum**

# **1 Features**

- Suited for wide operating range for battery applications
	- 2.9-V to 45-V input operating range
	- 48-V maximum output (50-V abs max)
	- $-$  Minimum boost supply voltage of 1.5 V when BIAS  $\geq 2.9$  V
	- Input transient protection up to 50 V
	- Minimized battery drain
		- Low shutdown current  $(I<sub>Q</sub> \le 2.6 \mu A)$
		- Low operating current ( $I_Q \leq 670 \mu A$ )
- Small solution size and low cost
	- Maximum switching frequency up to 2.2 MHz
	- 16-pin QFN package (3 mm × 3 mm)
	- Integrated error amplifier allows primary-side regulation without optocoupler (flyback)
	- Accurate current limit (see the *[Device](#page-2-0) [Comparison Table](#page-2-0)*)
- EMI mitigation
	- Selectable dual random spread spectrum
	- Lead-less package
- Higher efficiency with low-power dissipation
	- 45-mΩ R<sub>DSON</sub> switch
	- Fast switching, small switching loss
- Avoid AM band interference and crosstalk
	- Optional clock synchronization
	- Dynamically programmable wide switching frequency from 100 kHz to 2.2 MHz
- Integrated protection features
	- Constant current limiting over input voltage
	- Selectable hiccup mode overload protection
	- Programmable line UVLO
	- OVP protection
	- Thermal shutdown
- Accurate ±1% accuracy feedback reference
- Adjustable soft start
- PGOOD indicator
- Create a custom design using the LM5157x with the WEBENCH® [Power Designer](https://webench.ti.com/wb5/WBTablet/PartDesigner/quickview.jsp?base_pn=LM5157&origin=ODS&litsection=features)

# **2 Applications**

- [Battery-powered wide input boost, SEPIC, flyback](https://www.ti.com/applications/industrial/power-delivery/overview.html)  [converter](https://www.ti.com/applications/industrial/power-delivery/overview.html)
- [LED bias supply](https://www.ti.com/solution/automotive-rear-light)
- [Multiple-output flyback without optocoupler](https://www.ti.com/solution/hev-ev-inverter-motor-control)
- Portable speaker application
- Power module
- Industrial PLC
- Holdup capacitor charger
- [Audio amplifier power supply](https://www.ti.com/solution/wireless-speaker)
- Piezo driver/motor driver bias supply

# **3 Description**

The LM5157 device is a wide input range, nonsynchronous boost converter with integrated 50-V power switch.

The device can be used in boost, SEPIC, and flyback topologies. The device can start up from a single-cell battery with a minimum of 2.9 V. It can operate with an input supply voltage as low as 1.5 V if the BIAS pin is greater than 2.9 V.

The BIAS pin operates up to 45 V (50-V absolute maximum). The switching frequency is dynamically programmable with an external resistor from 100 kHz to 2.2 MHz. Switching at 2.2 MHz minimizes AM band interference and allows for a small solution size and fast transient response. To reduce the EMI of the power supply, the device provides a selectable Dual Random Spread Spectrum, which reduces the EMI over a wide frequency range.

The device features an accurate peak current limit over the input voltage, which avoids overdesigning power inductor. Low operating current and pulseskipping operation improve efficiency at light loads.

The device has built-in protection features such as overvoltage protection, line UVLO, thermal shutdown, and selectable Hiccup mode overload protection. Additional features include low shutdown  $I_{\Omega}$ , programmable soft start, precision reference, a power-good indicator, and external clock synchronization.

#### **Device Information**



(1) For all available packages, see the orderable addendum at the end of the data sheet.



**Typical Sepic Application**

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications,  $\overline{\textbf{41}}$  intellectual property matters and other important disclaimers. PRODUCTION DATA.



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# **4 Revision History**



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# **5 Device Comparison Table**



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# **6 Pin Configuration and Functions**



# **Figure 6-1. 16-Pin WQFN RTE Package (Top View)**

#### **Table 6-1. Pin Functions**



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#### **Table 6-1. Pin Functions (continued)**



(1)  $G =$  Ground, I = Input, O = Output, P = Power

# <span id="page-5-0"></span>**7 Specifications**

#### **7.1 Absolute Maximum Ratings**

Over the recommended operating junction temperature range<sup>(1)</sup>



(1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions.*  If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

(2) This pin is not specified to have an external voltage applied.

(3) Operating lifetime is de-rated when the pin voltage is greater than 5.5 V.

(4) The maximum current sink is limited to 1 mA when  $V_{PGOOD} > V_{BIAS}$ .

(5) This pin has an internal max voltage clamp which can handle up to 1.6 mA.

(6) High junction temperatures degrade operating lifetimes. Operating lifetime is de-rated for junction temperatures greater than 125°C.

### **7.2 ESD Ratings**



(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### **7.3 Recommended Operating Conditions**

Over the recommended operating junction temperature range $(1)$ 



(1) *Recommended Operating Conditions* are conditions under the device is intended to be functional. For specifications and test conditions, see *[Electrical Characteristics](#page-6-0)*.

(2) Boost converter output can be up to 48 V, but the SW pin voltage should be less than or equal to 50-V during transient.

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- (3) BIAS pin operating range is from 2.9 V to 45 V when VCC is supplied from the internal VCC regulator. When the VCC pin is directly connected to the BIAS pin, the device requires minimum 2.85 V at the BIAS pin to start up, and the BIAS pin operating range is from 2.75 V to 5.5 V after starting up.
- (4) Maximum switch currrent is limited by pre-programmed peak current limit (I<sub>LIM</sub>) , and is guaranteed when T<sub>J</sub> < T<sub>TSD</sub>.

#### **7.4 Thermal Information**



(1) For more information about traditional and new thermal metrics, see the *[Semiconductor and IC Package Thermal Metrics application](http://www.ti.com/lit/SPRA953) [report](http://www.ti.com/lit/SPRA953)*.

### **7.5 Electrical Characteristics**

Typical values correspond to T $_{\rm J}$  = 25°C. Minimum and maximum limits apply over T $_{\rm J}$  = –40°C to 125°C. Unless otherwise stated,  $V_{BIAS}$  = 12 V,  $R_T$  = 9.09 k $\Omega$ 





# **7.5 Electrical Characteristics (continued)**

Typical values correspond to T $_{\rm J}$  = 25°C. Minimum and maximum limits apply over T $_{\rm J}$  = –40°C to 125°C. Unless otherwise stated, V<sub>BIAS</sub> = 12 V, R<sub>T</sub> = 9.09 kΩ



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# **7.6 Typical Characteristics**











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# **8 Detailed Description**

### **8.1 Overview**

The LM5157x device is a wide input range, non-synchronous boost converter that uses peak-current-mode control. The device can be used in boost, SEPIC, and flyback topologies.

The device can start up from a single-cell battery with a minimum of 2.9 V. It can operate with input supply voltage as low as 1.5 V if the BIAS pin is greater than 2.9 V. The internal VCC regulator also supports BIAS pin operation up to 45 V (50-V absolute maximum). The switching frequency is dynamically programmable with an external resistor from 100 kHz to 2.2 MHz. Switching at 2.2 MHz minimizes AM band interference and allows for a small solution size and fast transient response. To reduce the EMI of the power supply, the device provides an optional dual random spread spectrum, which reduces the EMI over a wide frequency span.

The device features an accurate current limit over the input voltage range. Low operating current and pulse skipping operation improve efficiency at light loads.

The device also has built-in protection features such as overvoltage protection, line UVLO, and thermal shutdown. Selectable Hiccup mode overload protection protects the converter during prolonged current limit conditions. Additional features include the following:

- Low shutdown  $I_{\Omega}$
- Programmable soft start
- Precision reference
- Power good indicator
- **External clock synchronization**

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### **8.2 Functional Block Diagram**



#### **8.3 Feature Description**

#### **8.3.1 Line Undervoltage Lockout (UVLO/SYNC/EN Pin)**

The device has a dual-level EN/UVLO circuit. During power on, if the BIAS pin voltage is greater than 2.7 V and the UVLO pin voltage is between the enable threshold ( $V_{EN}$ ) and the UVLO threshold ( $V_{UVLO}$ ) for more than 1.5 µs (see [Section 8.3.6](#page-18-0) for more details), the device starts up and an internal configuration starts. The device typically requires a 90-µs internal start-up delay before entering Standby mode. In Standby mode, the VCC regulator and RT regulator are operational, the SS pin is grounded, and there is no switching at the SW pin.



**Figure 8-1. Line UVLO and Enable**

When the UVLO pin voltage is above the UVLO threshold, the device enters Run mode. In Run mode, a softstart sequence starts if the VCC voltage is greater than the VCC UV threshold (V<sub>VCC-UVLO</sub>). UVLO hysteresis is accomplished with an internal 50-mV voltage hysteresis and an additional 5-μA current source that is switched on or off. When the UVLO pin voltage exceeds the UVLO threshold, the UVLO hysteresis current source is enabled to quickly raise the voltage at the UVLO pin. When the UVLO pin voltage falls below the UVLO threshold, the current source is disabled, causing the voltage at the UVLO pin to fall quickly. When the UVLO pin voltage is less than the enable threshold ( $V_{EN}$ ), the device enters Shutdown mode after a 40-µs (typical) delay with all functions disabled.



**Figure 8-2. Boost Start-Up Waveforms Case 1: Start-Up by VCC UVLO, UVLO Toggle After Start-Up**





**Figure 8-3. Boost Start-Up Waveforms Case 2: Start-Up by VCC UVLO, EN Toggle After Start-Up**

The external UVLO resistor divider must be designed so that the voltage at the UVLO pin is greater than 1.5 V (typical) when the input voltage is in the desired operating range. The values of  $R_{UVLOT}$  and  $R_{UVLOB}$  can be calculated as shown in Equation 1 and Equation 2.

$$
R_{UVLOT} = \frac{V_{SUPPLY(ON)} \times \frac{V_{UVLO(FALLING)}}{V_{UVLO(RISING)}} - V_{SUPPLY(OFF)}}{I_{UVLO}}
$$
(1)

where

- $V_{\text{SUPPLY(ON)}}$  is the desired start-up voltage of the converter
- $V_{\text{SUPPLY(OFF)}}$  is the desired turn-off voltage of the converter

$$
R_{UVLOS} = \frac{V_{UVLO(RISING)} \times R_{UVLOT}}{V_{SUPPLY(ON)} - V_{UVLO(RISING)}}
$$

A UVLO capacitor ( $C_{UVLO}$ ) is required in case the input voltage drops below the  $V_{SUPPLY(OFF)}$  momentarily during start-up or during a severe load transient at the low input voltage. If the required UVLO capacitor is large, an additional series UVLO resistor ( $R_{UVLOS}$ ) can be used to quickly raise the voltage at the UVLO pin when the 5-μA hysteresis current turns on.

(2)





**Figure 8-4. Line UVLO using Three UVLO Resistors**

Do not leave the UVLO pin floating. Connect to the BIAS pin if not used.

#### **8.3.2 High Voltage VCC Regulator (BIAS, VCC Pin)**

The device has an internal wide input VCC regulator that is sourced from the BIAS pin. The wide input VCC regulator allows the BIAS pin to be connected directly to supply voltages from 2.9 V to 45 V (transient protection up to 50 V).

The VCC regulator turns on when the device is in Standby or Run mode. When the BIAS pin voltage is below the VCC regulation target, the VCC output tracks BIAS with a small dropout voltage. When the BIAS pin voltage is greater than the VCC regulation target, the VCC regulator provides a 5-V supply (typical) for the device and the internal N-channel MOSFET driver.

The VCC regulator sources current into the capacitor connected to the VCC pin. Connect a 5- $\Omega$  resistor in series with a 1-µF ceramic bypass capacitor from this pin to PGND.

The minimum supply voltage after start-up can be further decreased by supplying the BIAS pin from the boost converter output or from an external power supply as shown in Figure 8-5. Also, this configuration allows the device to handle more power when  $V_{\text{SUPPLY}}$  is less than 5 V. Practical minimum supply voltage after start-up is decided by the maximum duty cycle limit  $(D_{MAX})$ .



**Figure 8-5. Decrease the Minimum Operating Voltage After Start-Up**

In flyback topology, the internal power dissipation of the device can be decreased by supplying the BIAS using an additional transformer winding, especially in PSR flyback. In this configuration, the external BIAS supply voltage ( $V_{AUX}$ ) must be greater than the regulation target of the external LDO, and the BIAS pin voltage must always be greater than 2.9 V.





**Figure 8-6. External BIAS Supply (PSR Flyback)**

#### **8.3.3 Soft Start (SS Pin)**

The soft-start feature helps the converter gradually reach the steady state operating point, thus reducing start-up stresses and surges. The device regulates the FB pin to the SS pin voltage or the internal reference, whichever is lower.

At start-up, the internal 10-µA soft-start current source  $(I_{SS})$  turns on after the VCC voltage exceeds the VCC UV threshold. The soft-start current gradually increases the voltage on an external soft-start capacitor connected to the SS pin. This results in a gradual rise of the output voltage. The SS pin is pulled down to ground by an internal switch when the VCC is less than VCC UVLO threshold, the UVLO is less than the UVLO threshold, during Hiccup mode off time or thermal shutdown.

In boost topology, soft-start time  $(t_{SS})$  varies with the input supply voltage. The soft-start time in boost topology is calculated as shown in Equation 3.

$$
t_{SS} = \frac{C_{SS}}{I_{SS}} \times \left(1 - \frac{V_{SUPPLY}}{V_{LOAD}}\right)
$$
(3)

In SEPIC topology, the soft-start time  $(t_{SS})$  is calculated as follows.

$$
t_{SS} = \frac{C_{SS}}{l_{SS}}
$$
 (4)

TI recommends choosing the soft-start time long enough so that the converter can start up without going into an overcurrent state. See [Section 8.3.11](#page-23-0) for more detailed information.

[Figure 8-7](#page-17-0) shows an implementation of primary side soft start in flyback topology.

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**Figure 8-7. Primary-Side Soft Start in Flyback**

Figure 8-8 shows an implementation of secondary side soft-start in flyback topology.



**Figure 8-8. Secondary-Side Soft Start in Flyback**

#### **8.3.4 Switching Frequency (RT Pin)**

The switching frequency of the device can be set by a single RT resistor connected between the RT and the AGND pins. The resistor value to set the RT switching frequency ( $f_{RT}$ ) is calculated as shown in Equation 5.

$$
R_{T} = \frac{2.21 \times 10^{10}}{f_{RT(TYPICAL)}} - 955
$$
\n(5)

The RT pin is regulated to 0.5 V by the internal RT regulator when the device is enabled.

### **8.3.5 Dual Random Spread Spectrum – DRSS (MODE Pin)**

The device provides a digital spread spectrum, which reduces the EMI of the power supply over a wide frequency range. This function is enabled by a single resistor (37.4 kΩ or 100 kΩ) between the MODE pin and the AGND pin or by programming the MODE pin voltage (370 mV or greater than 1.0 V) during initial power up. When the spread spectrum is enabled, the internal modulator dithers the internal clock. When an external synchronization clock is applied to the SYNC pin, the internal spread spectrum is disabled. DRSS (a) combines a low frequency triangular modulation profile (b) with a high frequency cycle-by-cycle random modulation profile (c). The low frequency triangular modulation improves performance in lower radio frequency bands (for example, AM band), while the high frequency random modulation improves performance in higher radio frequency bands (for example, FM band). In addition, the frequency of the triangular modulation is further modulated randomly to reduce the likelihood of any audible tones. In order to minimize output voltage ripple caused by spread spectrum, duty cycle is modified on a cycle-by-cycle basis to maintain a nearly constant duty cycle when dithering is enabled (see [Figure 8-9\)](#page-18-0).

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**Figure 8-9. Dual Random Spread Spectrum**

#### **8.3.6 Clock Synchronization (UVLO/SYNC/EN Pin)**

The switching frequency of the device can be synchronized to an external clock by pulling down the EN/UVLO/ SYNC pin. The internal clock of the device is synchronized at the falling edge, but ignores the falling edge input during the forced off time, which is determined by the maximum duty cycle limit. The external synchronization clock must pull down the EN/UVLO/SYNC pin voltage below V<sub>UVLO(FALLING</sub>). The duty cycle of the pulldown pulse is not limited, but the minimum pulldown pulse width must be greater than 150 ns. The minimum pullup pulse width must be greater than 250 ns. Figure 8-10 shows an implementation of the remote shutdown function. The UVLO pin can be pulled down by a discrete MOSFET or an open-drain output of an MCU. In this configuration, the device stops switching immediately after the UVLO pin is grounded, and the device shuts down 40 µs (typical) after the UVLO pin is grounded.



**Figure 8-10. UVLO and Shutdown**

[Figure 8-11](#page-19-0) shows an implementation of shutdown and clock synchronization functions together. In this configuration, the device immediately stops switching when the UVLO pin is grounded, and the device shuts down if the f<sub>SYNC</sub> stays in high logic state for longer than 40 µs (typical). UVLO is in low logic state for more than 40 µs (typical). The device runs at  $f_{\text{SYNC}}$  if clock pulses are provided after the device is enabled.

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**Figure 8-11. UVLO, Shutdown, and Clock Synchronization**

Figure 8-13 and [Figure 8-14](#page-20-0) show implementations of standby and clock synchronization functions together. In this configuration, The device stops switching immediately if  $f_{SYNC}$  stays in high logic state and enters Standby mode if f<sub>SYNC</sub> stays in high logic state for longer than two switching cycles. The device runs at f<sub>SYNC</sub> if clock pulses are provided. Since the device can be enabled when the UVLO pin voltage is greater than the enable threshold for more than 1.5 µs, the configurations in Figure 8-13 and [Figure 8-14](#page-20-0) are recommended if the external clock synchronization pulses are provided from the start before the device is enabled. This 1.5-us requirement can be relaxed when the duty cycle of the synchronization pulse is greater than 50%. Figure 8-12 shows the required minimum duty cycle to start up by synchronization pulses. When the switching frequency is greater than 1.1 MHz, the UVLO pin voltage must be greater than the enable threshold for more than 1.5 µs before applying the external synchronization pulse.



**Figure 8-12. Required Duty Cycle to Start-Up by External Synchronization Clock**



**Figure 8-13. UVLO, Standby, and Clock Synchronization (a)**

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If the UVLO function is not required, the shutdown and clock synchronization functions can be implemented together by using one push-pull output of the MCU. In this configuration, the device shuts down if  $f_{\rm SYNC}$  stays in low logic state for longer than 40 µs (typical). The device is enabled if  $f_{SYNC}$  stays in high logic state for longer than 1.5 µs. The device runs at f<sub>SYNC</sub> if clock pulses are provided after the device is enabled. Also, in this configuration, it is recommended to apply the external clock pulses after the BIAS is supplied. By limiting the current flowing into the UVLO pin below 1 mA using a current limiting resistor, the external clock pulses can be supplied before the BIAS is supplied (see Figure 8-15).



**Figure 8-15. Shutdown and Clock Synchronization**

Figure 8-16 shows an implementation of inverted enable using external circuit.



**Figure 8-16. Inverted UVLO**

The external clock frequency ( $f_{SYNC}$ ) must be within +25% and -30% of  $f_{RT(TYPICAL)}$ . Since the maximum duty cycle limit and the peak current limit with a slope resistor  $(R_{\rm SI})$  are affected by the clock synchronization, take extra care when using the clock synchronization function. See Section 8.3.7 and [Section 8.3.12](#page-23-0) for more information.

#### **8.3.7 Current Sense and Slope Compensation**

The device senses switch current which flows into the SW pin, and provides a fixed internal slope compensation ramp, helping prevent subharmonic oscillation at high duty cycle. The internal slope compensation ramp is added to the sensed switch current for the PWM operation, but no slope compensation ramp is added to the



sensed inductor current for the current limit operation to provide an accurate peak current limit over the input supply voltage (see Figure 8-17).













Use Equation 6 to calculate the value of the peak slope voltage ( $V_{SLOPE}$ ).

$$
V_{SLOPE} = 500 \text{mV} \times \frac{f_{RT}}{f_{SYNC}}
$$

(6)

where

•  $f_{\text{SYNC}}$  is  $f_{\text{RT}}$  if clock synchronization is not used

According to peak current mode control theory, the slope of the compensation ramp must be greater than half of the sensed inductor current falling slope to prevent subharmonic oscillation at high duty cycle. Therefore, the minimum amount of slope compensation in boost topology must satisfy the following inequality:



(8)

$$
0.5 \times \frac{(V_{LOAD} + V_F) - V_{SUPPLY}}{L_M} \times A_{CS} \times Margin < 500 \text{mV} \times f_{SW}
$$
\n(7)

where

•  $V_F$  is a forward voltage drop of D1, the external diode

Typically, 82% of the sensed inductor current falling slope is known as an optimal amount of the slope compensation. By increasing the margin to 1.6, the amount of slope compensation becomes close to the optimal amount.

If clock synchronization is not used, the f<sub>SW</sub> frequency equals the f<sub>RT</sub> frequency. If clock synchronization is used, the  $f_{SW}$  frequency equals the  $f_{SYNC}$  frequency.

#### **8.3.8 Current Limit and Minimum On Time**

The device provides cycle-by-cycle peak current limit protection that turns off the internal MOSFET when the inductor current reaches the current limit threshold  $(I_{LIM})$ . To avoid an unexpected Hiccup mode operation during a harsh load transient condition, it is recommended to have more margin when programming the peak-current limit.

Boost converters have a natural pass-through path from the supply to the load through the high-side power diode (D1). Because of this path and the minimum on-time limitation of the device, boost converters cannot provide current limit protection when the output voltage is close to or less than the input supply voltage. The minimum on time is is calculated as Equation 8.

$$
t_{ON(MIN)} \approx \frac{800 \times 10^{-15}}{1}{\frac{1}{8 \times R_{T}} + 4 \times 10^{-6}}
$$

#### **8.3.9 Feedback and Error Amplifier (FB, COMP Pin)**

The feedback resistor divider is connected to an internal transconductance error amplifier that features high output resistance (R<sub>O</sub> = 10 MΩ) and wide bandwidth (BW = 7 MHz). The internal transconductance error amplifier sources current, which is proportional to the difference between the FB pin and the SS pin voltage or the internal reference, whichever is lower. The internal transconductance error amplifier provides symmetrical sourcing and sinking capability during normal operation and reduces its sinking capability when the FB is greater than OVP threshold.

To set the output regulation target, select the feedback resistor values as shown in Equation 9.

$$
V_{LOAD} = V_{REF} \times \left(\frac{R_{FBT}}{R_{FBB}} + 1\right)
$$
\n(9)

The output of the error amplifier is connected to the COMP pin, allowing the use of a Type 2 loop compensation network.  $R_{\text{COMP}}$ ,  $C_{\text{COMP}}$ , and optional  $C_{HF}$  loop compensation components configure the error amplifier gain and phase characteristics to achieve a stable loop response. The absolute maximum voltage rating of the FB pin is 4.0 V. If necessary, the feedback resistor divider input can be clamped by using an external zener diode.

The COMP pin features internal clamps. The maximum COMP clamp limits the maximum COMP pin voltage below its absolute maximum rating even in shutdown. The minimum COMP clamp limits the minimum COMP pin voltage to start switching as soon as possible during no load to heavy load transition. The minimum COMP clamp is disabled when FB is connected to ground in flyback topology.

#### **8.3.10 Power-Good Indicator (PGOOD Pin)**

The device has a power-good indicator (PGOOD) to simplify sequencing and supervision. The PGOOD switches to a high impedance open-drain state when the FB pin voltage is greater than the feedback undervoltage

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threshold ( $V_{UVTH}$ ), the VCC is greater than the VCC UVLO threshold and the UVLO/EN is greater than the EN threshold. A 25-μs deglitch filter prevents any false pulldown of the PGOOD due to transients. The recommended minimum pullup resistor value is 10 kΩ.

Due to the internal diode path from the PGOOD pin to the BIAS pin, the PGOOD pin voltage cannot be greater than  $V_{BIAS}$  + 0.3 V.

#### **8.3.11 Hiccup Mode Overload Protection (MODE Pin)**

To further protect the converter during prolonged current limit conditions, the device provides selectable Hiccup mode overload protection. This function is enabled by a single resistor (37.4 kΩ or 62.0 kΩ) between the MODE pin and the AGND pin or by programming the MODE pin voltage (370 mV or 620 mV) during initial power up. The internal Hiccup mode fault timer of the device counts the PWM clock cycles when the cycle-by-cycle current limiting occurs after soft start is finished. When the Hiccup mode fault timer detects 64 cycles of current limiting, an internal Hiccup mode off timer forces the device to stop switching and pulls down SS. Then, the device restarts after 32768 cycles of Hiccup mode off time. The 64-cycle Hiccup mode fault timer is reset if eight consecutive switching cycles occur without exceeding the current limit threshold. The soft-start time must be long enough not to trigger the Hiccup mode protection after the soft start is finished.



**Figure 8-20. Hiccup Mode Overload Protection**

#### **8.3.12 Maximum Duty Cycle Limit and Minimum Input Supply Voltage**

The practical duty cycle is greater than the estimated due to voltage drops across the MOSFET and sense resistor. The estimated duty cycle is calculated as shown in Equation 10.

$$
D = 1 - \frac{V_{\text{SUPPLY}}}{V_{\text{LOAD}} + V_{\text{F}}}
$$
(10)

When designing boost converters, the maximum required duty cycle must be reviewed at the minimum supply voltage. The minimum input supply voltage that can achieve the target output voltage is limited by the maximum duty cycle limit, and it can be estimated as follows:

$$
V_{SUPPLY(MIN)} \approx (V_{LOAD} + V_F) \times (1 - D_{MAX}) + I_{SUPPLY(MAX)} \times R_{DCR} + I_{SUPPLY(MAX)} \times 110m \times D_{MAX}
$$
\n(11)

where

- $I_{\text{SUPPLY}(\text{MAX})}$  is the maximum input current
- $R_{DCR}$  is the DC resistance of the inductor

$$
D_{MAX1} = 1 - 0.1 \times \frac{f_{SYNC}}{f_{RT}}
$$
 (12)

$$
D_{MAX2} = 1 - 100 \text{ns} \times f_{SW} \tag{13}
$$

The minimum input supply voltage can be further decreased by supplying  $f_{\text{SYNC}}$ , which is less than  $f_{\text{RT}}$ . Practical  $D_{MAX}$  is  $D_{MAX1}$  or  $D_{MAX2}$ , whichever is lower.

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#### **8.3.13 Internal MOSFET (SW Pin)**

The device provides an internal switch with an  $r_{DS(ON)}$  that is typically 45 mΩ when the BIAS pin is greater than 5 V. The  $r_{DS(ON)}$  of the internal switch is increased when the BIAS pin is less than 5 V. The device temperature must be checked at the minimum supply voltage especially when the BIAS pin is less than 5 V.

The dV/dT of the SW pin must be limited during the 90-µs internal start-up delay to avoid a false turn-on, which is caused by the coupling through  $C_{DG}$  parasitic capacitance of the internal MOSFET switch.

#### **8.3.14 Overvoltage Protection (OVP)**

The device has OVP for the output voltage. OVP is sensed at the FB pin. If the voltage at the FB pin rises above the overvoltage threshold ( $V_{\text{OVTH}}$ ), OVP is triggered and switching stops. During OVP, the internal error amplifier is operational, but the maximum source and sink capability is decreased to 60 µA.

#### **8.3.15 Thermal Shutdown (TSD)**

An internal thermal shutdown turns off the VCC regulator, disables switching, and pulls down the SS when the junction temperature exceeds the thermal shutdown threshold  $(T_{\text{TSD}})$ . After the junction temperature is decreased by 15°C, the VCC regulator is enabled again and the device performs a soft start.

#### **8.4 Device Functional Modes**

#### **8.4.1 Shutdown Mode**

If the UVLO/EN/SYNC pin voltage is below  $V_{EN}$  for longer than 40  $\mu$ s (typical), the device goes into Shutdown mode with all functions disabled. In Shutdown mode, the device decreases the BIAS pin current consumption to below 2.6 μA (typical).

#### **8.4.2 Standby Mode**

If the UVLO/EN/SYNC pin voltage is greater than  $V_{EN}$  and below  $V_{UVLO}$  for longer than 1.5 µs, the device enters Standby mode with the VCC regulator operational, RT regulator operational, SS pin grounded, and no switching. The PGOOD is activated when the VCC voltage is greater than the VCC UV threshold.

#### **8.4.3 Run Mode**

If the UVLO pin voltage is above  $V_{UVLO}$  and the VCC voltage is sufficient, the device enters Run mode.

#### *8.4.3.1 Spread Spectrum Enabled*

The spread spectrum function is enabled by a single resistor (37.4 kΩ ±5% or 100 kΩ ±5%) between the MODE pin and the AGND pin or by programming the MODE pin voltage (370 mV ±10% or greater than 1.0 V) during initial power up. To switch the spread spectrum function, EN must be grounded for more than 60 µs, or VCC must be fully discharged.

#### *8.4.3.2 Hiccup Mode Protection Enabled*

The Hiccup mode protection is enabled by a single resistor (37.4 k $\Omega$  ±5% or 62.0 k $\Omega$  ±5%) between the MODE pin and the AGND pin or by programming the MODE pin voltage (370 mV ±10% or 620 mV ±10%) during initial power up. To switch the Hiccup mode protection function, EN should be grounded for more than 60 µs, or VCC must be fully discharged.

<span id="page-25-0"></span>

# **9 Application and Implementation**

#### **Note**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### **9.1 Application Information**

TI provides three application notes that explain how to design boost, SEPIC, and flyback converters using the device. These comprehensive application notes include component selections and loop response optimization.

See these application reports for more information on loop response and component selection:

- *[How to Design a Boost Converter Using LM5157x](https://www.ti.com/lit/pdf/SNVA824)*
- *[How to Design an Isolated Flyback Converter Using LM5157x](https://www.ti.com/lit/pdf/SNVA866)*
- *[How to Design a SEPIC Converter Using LM5157x](https://www.ti.com/lit/pdf/SNVA868)*

#### **9.2 Typical Application**

Figure 9-1 shows all optional components to design a boost converter.



**Figure 9-1. Typical Boost Converter Circuit With Optional Components**

#### **9.2.1 Design Requirements**

Table 9-1 shows the intended input, output, and performance parameters for this application example.

**Table 9-1. Design Example Parameters**

<b>DESIGN PARAMETER</b>	<b>VALUE</b>
Minimum input supply voltage (V <sub>SUPPLY(MIN)</sub> )	6 V
Target output voltage $(V_{\text{LOAD}})$	12 V
Maximum load current $(Il$ $_{\text{OAD}})$	1.6 A (≈ 19.2 Watt)
Typical switching frequency $(f_{SW})$	2100 kHz

#### **9.2.2 Detailed Design Procedure**

Use the Quick Start Calculator to expedite the process of designing of a regulator for a given application. Download these Quick Start Calculator for more information on loop response and component selection:

- *[LM5157x Boost Quick Start Calculator](http://www.ti.com/lit/zip/TBD)*
- *[LM5157x Flyback Quick Start Calculator](http://www.ti.com/lit/zip/TBD)*



#### • *[LM5157x SEPIC Quick Start Calculator](http://www.ti.com/lit/zip/TBD)*

The device is also WEBENCH® Designer enabled. The WEBENCH software uses an iterative design procedure and accesses comprehensive data bases of components when generating a design.

#### *9.2.2.1 Custom Design With WEBENCH® Tools*

[Click here](https://webench.ti.com/wb5/WBTablet/PartDesigner/quickview.jsp?base_pn=LM5157&origin=ODS&litsection=application) to create a custom design using the device with the WEBENCH® Power Designer.

- 1. Start by entering the input voltage (V<sub>IN</sub>), output voltage (V<sub>OUT</sub>), and output current ( $I_{\text{OUT}}$ ) requirements.
- 2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
- 3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at [www.ti.com/WEBENCH.](http://www.ti.com/lsds/ti/analog/webench/overview.page?DCMP=sva_web_webdesigncntr_en&HQS=sva-web-webdesigncntr-vanity-lp-en)

#### *9.2.2.2 Recommended Components*

Table 9-2 shows a recommended list of materials for this typical application.



#### **Table 9-2. List of Materials**

<span id="page-27-0"></span>

**Table 9-2. List of Materials (continued)**



(1) See the *[Third-Party Products Disclaimer](#page-35-0)*.

#### *9.2.2.3 Inductor Selection (LM)*

When selecting the inductor, consider three key parameters: inductor current ripple ratio (RR), falling slope of the inductor current, and RHP zero frequency  $(f_{RHP})$ .

Inductor current ripple ratio is selected to have a balance between core loss and copper loss. The falling slope of the inductor current must be low enough to prevent subharmonic oscillation at high duty cycle (additional R<sub>SL</sub> resistor is required if not). Higher  $f_{RHP}$  (lower inductance) allows a higher crossover frequency and is always preferred when using a small value output capacitor.

The inductance value can be selected to set the inductor current ripple between 30% and 70% of the average inductor current as a good compromise between  $RR$ ,  $F_{RHP}$ , and inductor falling slope.

#### *9.2.2.4 Output Capacitor (COUT)*

There are a few ways to select the proper value of output capacitor  $(C_{OUT})$ . The output capacitor value can be selected based on output voltage ripple, output overshoot, or undershoot due to load transient.

The ripple current rating of the output capacitors must be enough to handle the output ripple current. By using multiple output capacitors, the ripple current can be split. In practice, ceramic capacitors are placed closer to the diode and the MOSFET than the bulk aluminum capacitors in order to absorb the majority of the ripple current.

#### *9.2.2.5 Input Capacitor*

The input capacitors decrease the input voltage ripple. The required input capacitor value is a function of the impedance of the source power supply. More input capacitors are required if the impedance of the source power supply is not low enough.

#### *9.2.2.6 Diode Selection*

A Schottky is the preferred type for a D1 diode due to its low forward voltage drop and small reverse recovery charge. Low reverse leakage current is an important parameter when selecting the Schottky diode. The diode must be rated to handle the maximum output voltage plus any switching node ringing. Also, it must be able to handle the average output current.

#### **9.2.3 Application Curve**



**Figure 9-2. Efficiency versus Output Current**

<span id="page-28-0"></span>

### **9.3 System Examples**



**Figure 9-3. Typical Boost Application**



**Figure 9-4. Typical Start-Stop Application**









**Figure 9-6. Typical SEPIC Application**



**Figure 9-7. LiDAR Bias Supply 1 (DCM Operation)**



**Figure 9-8. LiDAR Bias Supply 2 (CCM Operation)**





**Figure 9-9. Low-Cost Single String LED Driver**



**Figure 9-10. Secondary-Side Regulated Isolated Flyback**





**Figure 9-11. Primary-Side Regulated Multiple-Output Isolated Flyback/Isolated SEPIC**



**Figure 9-12. Typical Non-Isolated Flyback**

<span id="page-32-0"></span>

# **10 Power Supply Recommendations**

The device is designed to operate from a power supply or a battery whose voltage range is from 1.5 V to 45 V. The input power supply must be able to supply the maximum boost supply voltage and handle the maximum input current at 1.5 V. The impedance of the power supply and battery including cables must be low enough that an input current transient does not cause an excessive drop. Additional input ceramic capacitors can be required at the supply input of the converter.

<span id="page-33-0"></span>

# **11 Layout**

# **11.1 Layout Guidelines**

The performance of switching converters heavily depends on the quality of the PCB layout. The following guidelines will help users design a PCB with the best power conversion performance, thermal performance, and minimize generation of unwanted EMI.

- Put the D1 component on the board first.
- Use a small size ceramic capacitor for  $C_{\text{OUT}}$ .
- Make the switching loop ( $C_{\text{OUT}}$  to D1 to SW to PGND to  $C_{\text{OUT}}$ ) as small as possible.
- Leave a copper area near the D1 diode for thermal dissipation.
- Put the  $R_{VCC}$  resistor in series with the  $C_{VCC}$  capacitor as near the device as possible between the VCC and PGND pins.
- Connect the COMP pin to the compensation components  $(R_{\text{COMP}}$  and  $C_{\text{COMP}}$ ).
- Connect the  $C_{\text{COMP}}$  capacitor to the analog ground trace.
- Connect the AGND pin directly to the analog ground plane. Connect the AGND pin to the R<sub>MODE</sub>, R<sub>UVLOB</sub>, R<sub>T</sub>,  $C_{SS}$ , and  $R_{FBB}$  components.
- Connect the exposed pad to the AGND pin under the device.
- Add several vias under the exposed pad to help conduct heat away from the device. Connect the vias to a large ground plane on the bottom layer.

<span id="page-34-0"></span>

# **11.2 Layout Examples**





<span id="page-35-0"></span>

# **12 Device and Documentation Support**

### **12.1 Device Support**

#### **12.1.1 Third-Party Products Disclaimer**

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#### **12.1.2 Development Support**

#### *12.1.2.1 Custom Design With WEBENCH® Tools*

[Click here](https://webench.ti.com/wb5/WBTablet/PartDesigner/quickview.jsp?base_pn=LM5157&origin=ODS&litsection=device_support) to create a custom design using the LM5157x device with the WEBENCH® Power Designer.

- 1. Start by entering the input voltage  $(V_{\text{IN}})$ , output voltage  $(V_{\text{OUT}})$ , and output current  $(I_{\text{OUT}})$  requirements.
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The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at [www.ti.com/WEBENCH.](http://www.ti.com/lsds/ti/analog/webench/overview.page?DCMP=sva_web_webdesigncntr_en&HQS=sva-web-webdesigncntr-vanity-lp-en)

#### **12.1.3 Export Control Notice**

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#### **12.2 Documentation Support**

#### **12.2.1 Related Documentation**

For related documentation see the following:

- Texas Instruments, *[How to Design a Boost Converter Using LM5157x](https://www.ti.com/lit/pdf/SNVA824)*
- Texas Instruments, *[How to Design an Isolated Flyback Converter Using LM5157x](https://www.ti.com/lit/pdf/SNVA866)*
- Texas Instruments, *[How to Design a SEPIC Converter Using LM5157x](https://www.ti.com/lit/pdf/SNVA868)*
- Texas Instruments, *[LM5157EVM-BST User's Guide](https://www.ti.com/lit/pdf/SNVU000)*
- Texas Instruments, *[LM5157EVM-FLY User's Guide](https://www.ti.com/lit/pdf/SNVU000)*
- Texas Instruments, *[LM5157EVM-SEPIC User's Guide](https://www.ti.com/lit/pdf/SNVU000)*

#### **12.3 Receiving Notification of Documentation Updates**

To receive notification of documentation updates, navigate to the device product folder on [ti.com.](https://www.ti.com) Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### **12.4 Support Resources**

TI E2E™ [support forums](https://e2e.ti.com) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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#### **12.6 Electrostatic Discharge Caution**



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### **12.7 Glossary**

[TI Glossary](https://www.ti.com/lit/pdf/SLYZ022) This glossary lists and explains terms, acronyms, and definitions.

<span id="page-37-0"></span>

# **13 Mechanical, Packaging, and Orderable Information**

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



### **PACKAGING INFORMATION**



**(1)** The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures. "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

**(3)** MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

**(4)** There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

**(5)** Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

**(6)** Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### **OTHER QUALIFIED VERSIONS OF LM5157 :**

• Automotive : [LM5157-Q1](http://focus.ti.com/docs/prod/folders/print/lm5157-q1.html)

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects



**TEXAS** 

### **TAPE AND REEL INFORMATION**

**ISTRUMENTS** 





#### **QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**





#### Pack Materials-Page 1



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# **PACKAGE MATERIALS INFORMATION**



\*All dimensions are nominal



# **GENERIC PACKAGE VIEW**

# **RTE 16 WQFN - 0.8 mm max height**

**3 x 3, 0.5 mm pitch** PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.







# **PACKAGE OUTLINE**

# **RTE0016C WQFN - 0.8 mm max height**

PLASTIC QUAD FLATPACK - NO LEAD



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



# **EXAMPLE BOARD LAYOUT**

# **RTE0016C WQFN - 0.8 mm max height**

PLASTIC QUAD FLATPACK - NO LEAD



4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



# **EXAMPLE STENCIL DESIGN**

# **RTE0016C WQFN - 0.8 mm max height**

PLASTIC QUAD FLATPACK - NO LEAD



6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate

design recommendations.



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